

3 V, SUPER MINIMOLD  
MEDIUM POWER SI MMIC AMPLIFIER

## FEATURES

- HIGH  $P_{1dB}$ : 7 dBm TYP at 1.9 GHz
- LOW VOLTAGE: 3.0 V TYP, 2.7 V MIN
- WIDE BANDWIDTH: 2.9 GHz at -3 dB
- SUPER SMALL PACKAGE: SOT-363 package
- TAPE AND REEL PACKAGING OPTION AVAILABLE

## DESCRIPTION

The UPC2762TB is a Silicon Monolithic integrated circuit which is manufactured using the NESAT™ III process. The NESAT™ III process produces transistors with  $f_T$  approaching 20 GHz. The UPC2762TB is pin compatible and has comparable performance to the larger UPC2762T, so it is suitable for use as a replacement to help reduce system size. The IC is housed in a 6 pin super minimold or SOT-363 package. Operating on a 3 volt supply, this IC is ideally suited for handheld, portable designs.

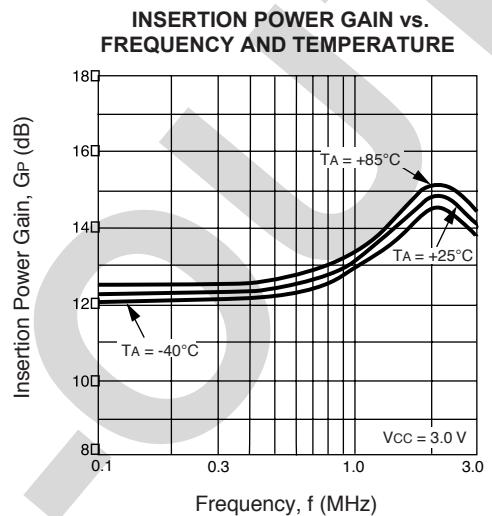
Stringent quality assurance and test procedures ensure the highest reliability and performance.

## ELECTRICAL CHARACTERISTICS (TA = 25°C, ZL = Zs = 50Ω, Vcc = 3.0 V)

PART NUMBER PACKAGE OUTLINE		UPC2762TB S06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP
Icc	Circuit Current (no signal)	mA		27 35
Gs	Small Signal Gain, f = 900 MHz f = 1900 MHz	dB dB	11 11.5	13 15.5
fu	Upper Limit Operating Frequency (The gain at fu is 3 dB down from the gain at 0.1 GHz)	GHz	2.7	2.9
P1dB	Output Power at 1 dB Compression Point, f = 900 MHz f = 1900 MHz	dBm dBm	+5.5 +4.5	+8 +7
Psat	Saturated Output Power, f = 900 MHz f = 1900 MHz	dBm dBm		9 8.5
NF	Noise Figure, f = 900 MHz f = 1900 MHz	dB dB		6.5 7
RLin	Input Return Loss, f = 900 MHz f = 1900 MHz	dB dB	6 5.5	9 8.5
RLout	Output Return Loss, f = 900 MHz f = 1900 MHz	dB dB	8 9	11 12
ISOL	Isolation, f = 900 MHz f = 1900 MHz	dB dB	22 20	27 25
OIP3	SSB Output Third Order Intercept Point f = 900, 902 MHz Pout = +4 dBm f = 1900, 1902 MHz	dBm dBm		+12 +9
Padj	Adjacent Channel Power, f = 900 MHz, π/4 QPSK wave <sup>1</sup> , Δf = ±50 KHz f = 900 MHz, π/4 QPSK wave <sup>1</sup> , Δf = ±100 KHz Po = +4 dBm	dBc dBc		-64 -64

Note:

1. π/4 QPSK modulated wave input, data rate 42 kbps.



**ABSOLUTE MAXIMUM RATINGS<sup>1</sup>** ( $T_A = 25^\circ\text{C}$ )

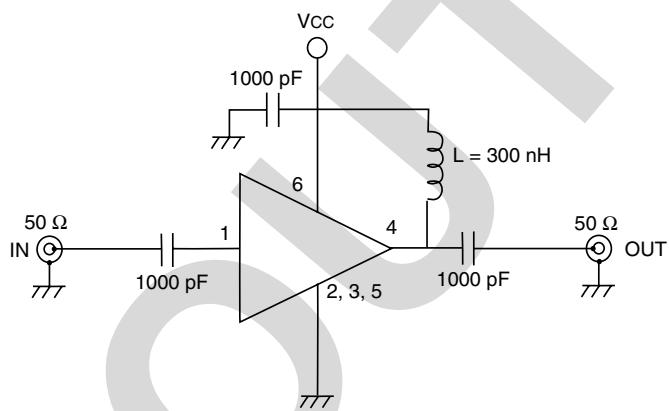
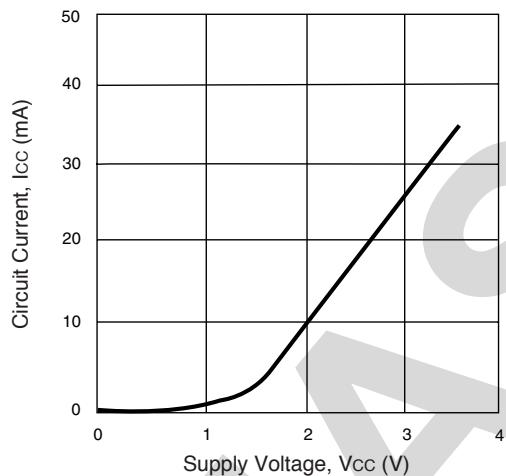
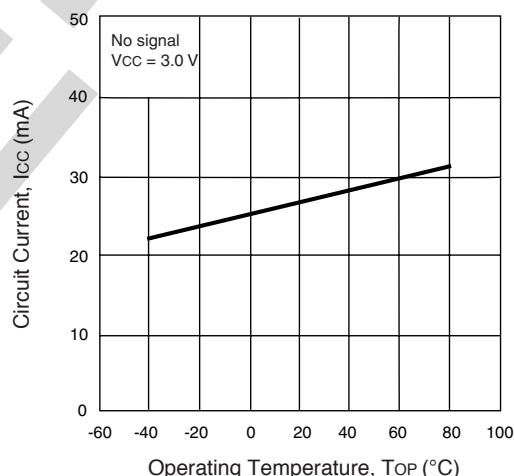
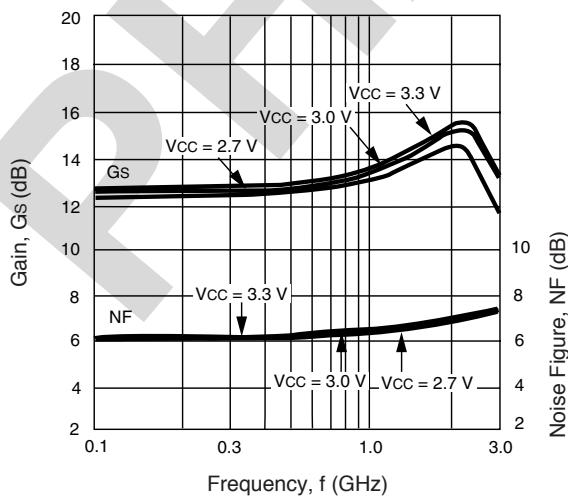
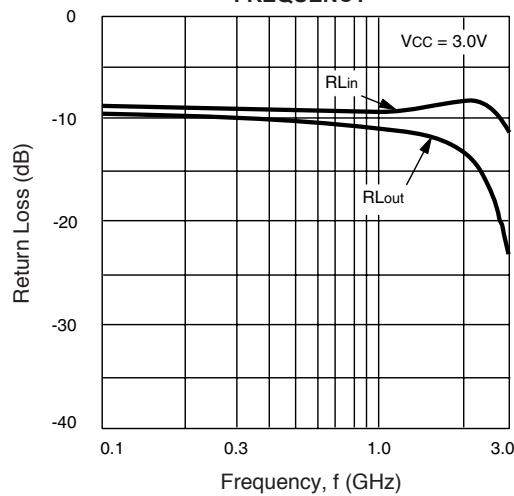
SYMBOLS	PARAMETERS	UNITS	RATINGS
V <sub>CC</sub>	Supply Voltage	V	3.6
I <sub>CC</sub>	Total Supply Current	mA	70
P <sub>IN</sub>	Input Power	dBm	+10
P <sub>T</sub>	Total Power Dissipation <sup>2</sup>	mW	270
T <sub>OP</sub>	Operating Temperature	°C	-40 to +85
T <sub>TSG</sub>	Storage Temperature	°C	-55 to +150

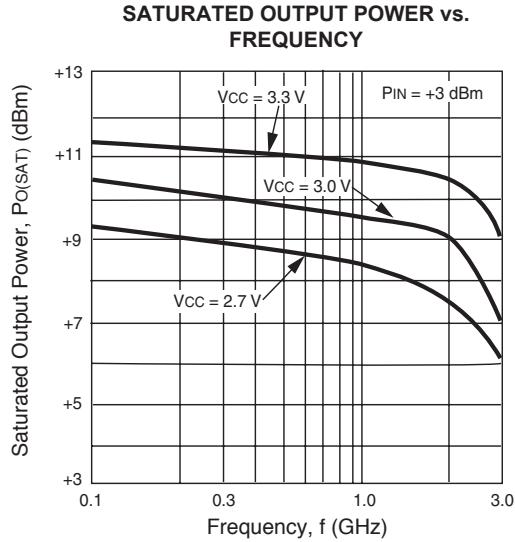
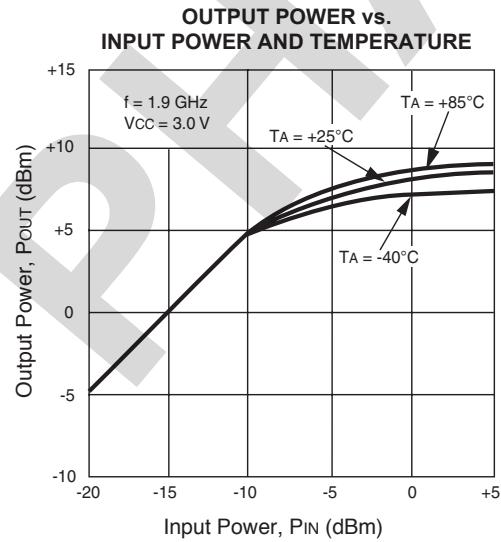
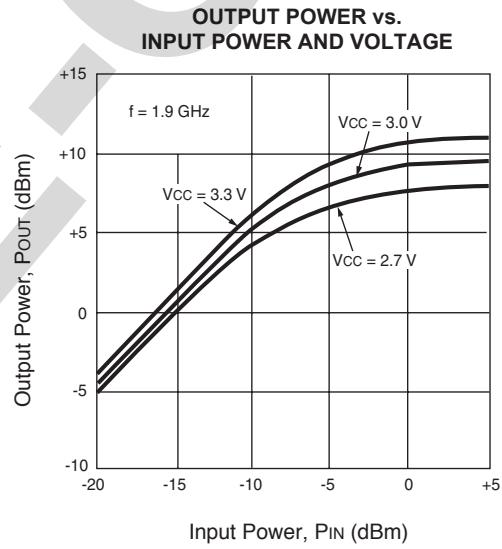
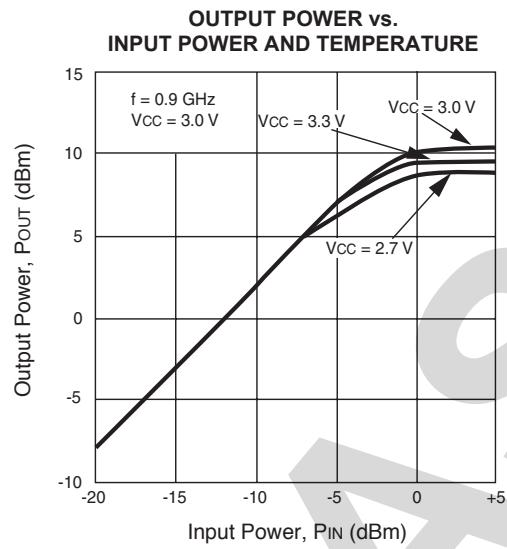
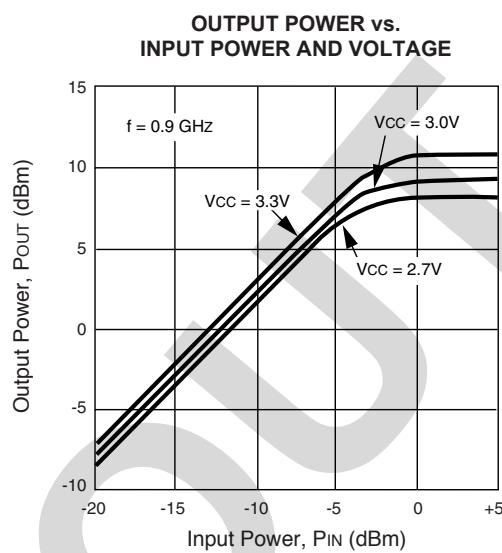
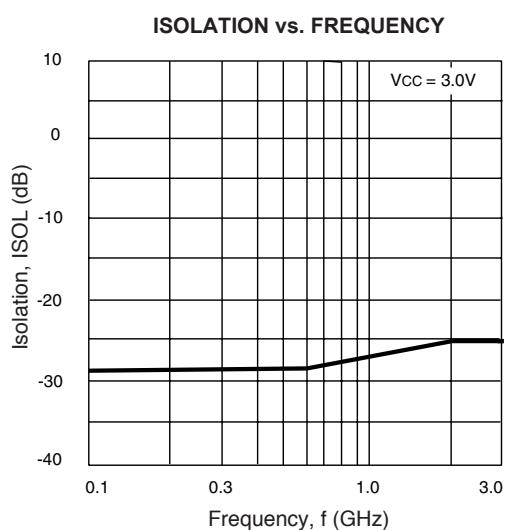
## Notes:

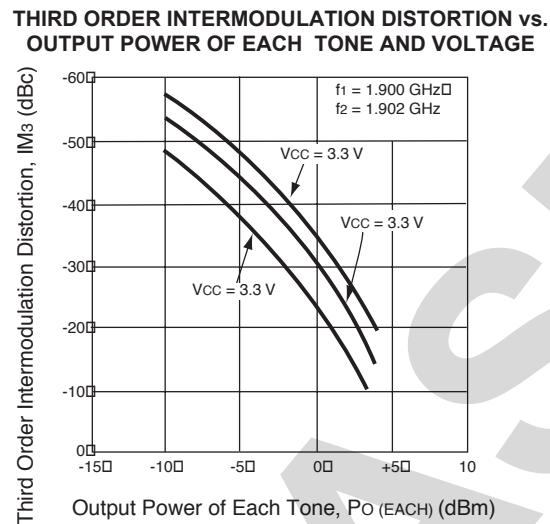
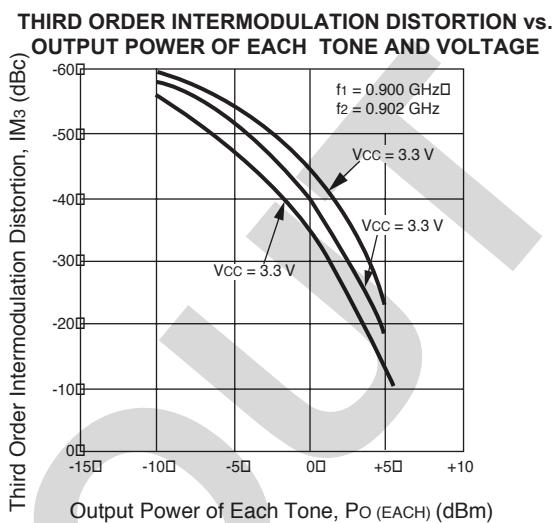
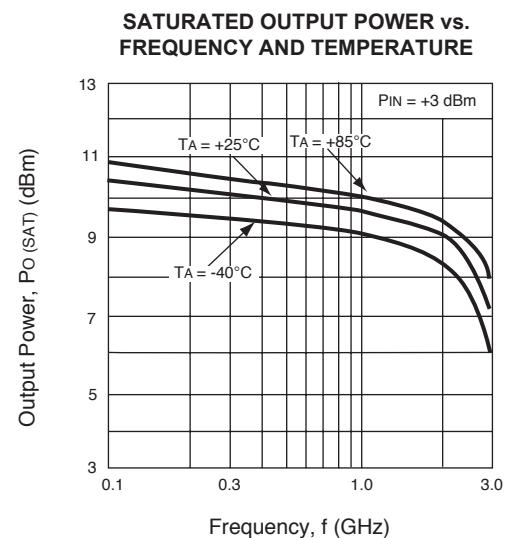
1. Operation in excess of any one of these parameters may result in permanent damage.
2. Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB ( $T_A = 85^\circ\text{C}$ ).

**RECOMMENDED OPERATING CONDITIONS**

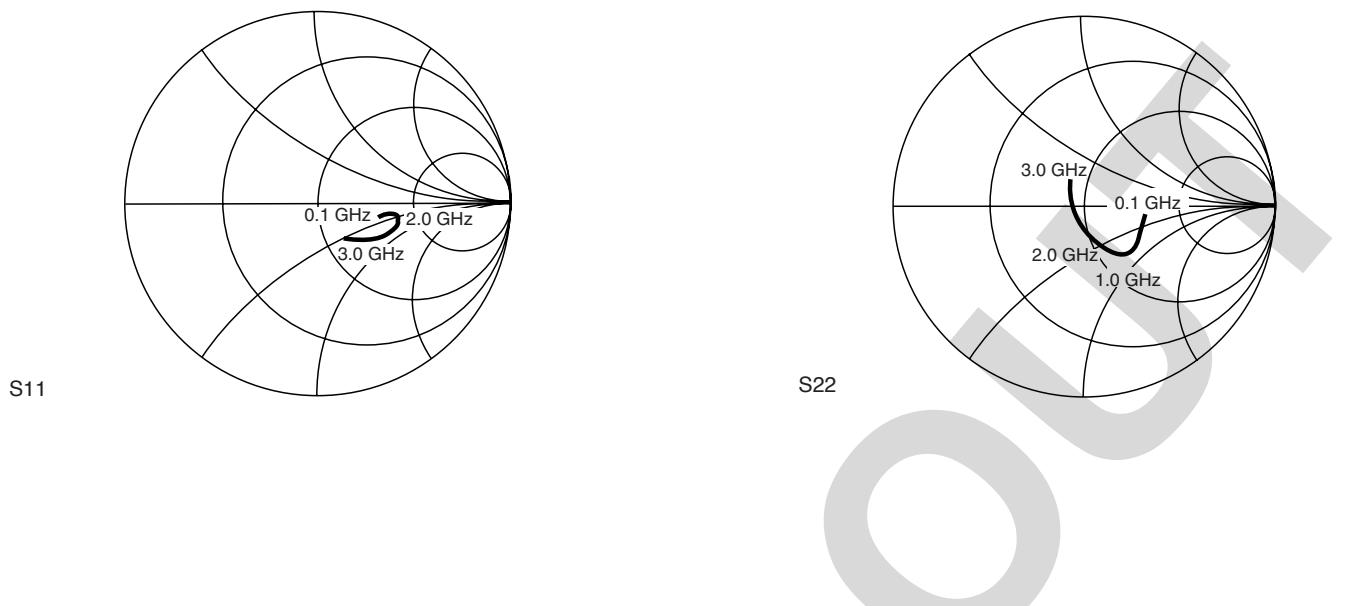
SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
V <sub>CC</sub>	Supply Voltage	V	2.7	3	3.3
T <sub>OP</sub>	Operating Temperature	°C	-40	25	85

**TEST CIRCUIT****TYPICAL PERFORMANCE CURVES** ( $T_A = 25^\circ\text{C}$ )CIRCUIT CURRENT vs.  
SUPPLY VOLTAGECIRCUIT CURRENT vs.  
OPERATING TEMPERATURENOISE FIGURE AND  
INSERTION POWER GAIN vs.  
FREQUENCY AND VOLTAGEINPUT AND OUTPUT  
RETURN LOSS vs.  
FREQUENCY

**TYPICAL PERFORMANCE CURVES (TA = 25°C)**

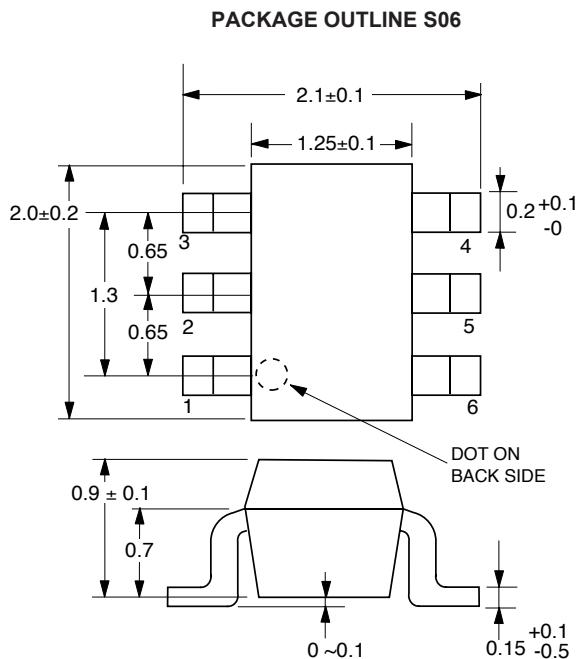
**TYPICAL PERFORMANCE CURVES (TA = 25°C)**

## TYPICAL SCATTERING PARAMETERS (TA = +25°C, VCC = VOUT = 3.0 V)

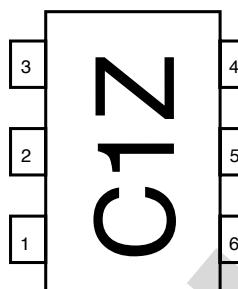


VCC = VOUT = 3.0 V, Icc = 29 mA

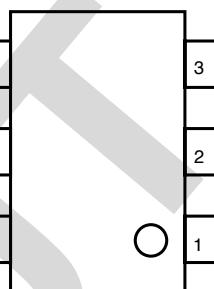
FREQUENCY GHz	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>		K
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
0.1	0.338	-1.3	4.560	-3.4	0.039	1.0	0.310	-5.5	2.23
0.2	0.346	-2.0	4.581	-7.6	0.039	2.7	0.311	-9.5	2.20
0.3	0.348	-1.2	4.616	-11.3	0.039	6.8	0.302	-12.3	2.20
0.4	0.340	-1.9	4.661	-15.8	0.040	8.1	0.296	-16.2	2.18
0.5	0.329	-3.1	4.689	-19.5	0.040	11.6	0.290	-20.2	2.20
0.6	0.324	-6.2	4.726	-23.6	0.041	13.7	0.292	-24.1	2.12
0.7	0.341	-8.1	4.844	-27.4	0.042	15.8	0.291	-26.2	2.01
0.8	0.359	-7.6	4.927	-31.5	0.043	18.1	0.292	-28.3	1.90
0.9	0.378	-6.5	5.057	-35.8	0.044	19.3	0.284	-30.9	1.77
1.0	0.375	-5.1	5.179	-41.0	0.045	20.3	0.280	-35.3	1.72
1.1	0.363	-5.2	5.306	-45.9	0.047	22.1	0.285	-40.0	1.64
1.2	0.353	-6.7	5.400	-51.0	0.047	23.7	0.288	-43.4	1.62
1.3	0.357	-8.8	5.567	-56.5	0.048	26.1	0.288	-45.7	1.54
1.4	0.377	-11.7	5.706	-61.7	0.049	24.5	0.285	-47.9	1.44
1.5	0.402	-12.7	5.820	-68.0	0.052	26.7	0.282	-52.8	1.32
1.6	0.414	-13.2	5.987	-73.7	0.052	26.8	0.285	-58.1	1.27
1.7	0.426	-13.6	6.081	-80.1	0.055	29.0	0.288	-62.0	1.18
1.8	0.434	-16.1	6.182	-86.7	0.056	28.2	0.291	-66.1	1.14
1.9	0.448	-19.0	6.229	-93.2	0.057	28.5	0.286	-70.4	1.09
2.0	0.463	-21.7	6.328	-99.7	0.057	28.0	0.282	-76.2	1.07
2.1	0.483	-23.9	6.382	-106.7	0.058	28.5	0.282	-81.5	1.01
2.2	0.492	-25.8	6.431	-113.8	0.058	29.0	0.282	-86.9	0.99
2.3	0.492	-29.7	6.424	-121.2	0.060	30.1	0.278	-91.7	0.99
2.4	0.486	-34.6	6.329	-128.8	0.060	30.2	0.268	-98.4	1.01
2.5	0.489	-40.4	6.146	-136.1	0.062	31.1	0.260	-104.5	1.02
2.6	0.500	-44.6	5.997	-143.1	0.061	32.1	0.251	-111.3	1.05
2.7	0.511	-48.5	5.822	-149.9	0.064	31.4	0.248	-116.7	1.03
2.8	0.511	-50.4	5.693	-157.0	0.066	34.0	0.237	-121.5	1.04
2.9	0.494	-52.9	5.553	-163.0	0.065	33.8	0.222	-128.3	1.11
3.0	0.465	-55.9	5.334	-169.5	0.065	35.5	0.203	-134.5	1.20
3.1	0.441	-60.6	5.157	-175.5	0.066	35.5	0.189	-141.1	1.27

**OUTLINE DIMENSIONS** (Units in mm)**LEAD CONNECTIONS**

(Top View)



(Bottom View)



1. INPUT
2. GND
3. GND
4. OUTPUT
5. GND
6. Vcc

**PIN DESCRIPTIONS**

Pin No.	Pin Name	Applied Voltage (V)	Description	Internal Equivalent Circuit
1	Input	—	Signal input pin. An internal matching circuit, configured with resistors, enables $50\ \Omega$ connection over a wide bandwidth. A multi-feedback circuit is designed to cancel the deviations of $h_{FE}$ and resistance. This pin must be coupled to the signal source with a blocking capacitor.	
4	Output		Signal output pin. Connect an inductor between this pin and Vcc to supply current to the internal output transistors.	
6	Vcc	2.7 to 3.3	Power supply pin. This pin should be externally equipped with a bypass capacitor to minimize ground impedance.	
2 3 5	GND	0	Ground pins. These pins should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to minimize impedance difference.	

**ORDERING INFORMATION**

PART NUMBER	QTY
UPC2762TB-E3-A	3K/Reel

Note:

Embossed Tape, 8 mm wide. Pins 1, 2 and 3 face perforated side

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